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HALOGEN

FREE



## **Quad SPST CMOS Analog Switches**

#### **DESCRIPTION**

The DG441, DG442 monolithic quad analog switches are designed to provide high speed, low error switching of analog and audio signals. The DG441 has a normally closed function. The DG442 has a normally open function. Combining low on-resistance (50  $\Omega$ , typ.) with high speed (t<sub>ON</sub> 150 ns, typ.), the DG441, DG442 are ideally suited for upgrading DG201A/202 sockets. Charge injection has been minimized on the drain for use in sample-and-hold circuits.

To achieve high voltage ratings and superior switching performance, the DG441, DG442 are built on Vishay Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply levels when off.

#### **FEATURES**

- Halogen-free according to IEC 61249-2-21 Definition
- Low on-resistance: 50  $\Omega$
- Low leakage: 80 pA
- Low power consumption: 0.2 mW
- Fast switching action t<sub>ON</sub>: 150 ns
- Low charge injection Q: 1 pC
- DG201A/DG202 upgrades
- TTL/CMOS-compatible logic
- Single supply capability
- Compliant to RoHS Directive 2002/95/EC

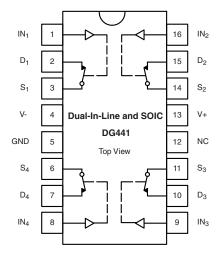
#### **BENEFITS**

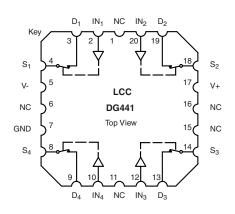
- Less signal errors and distortion
- Reduced power supply requirements
- Faster throughput
- Improved reliability
- Reduced pedestal errors
- Simplifies retrofit
- Simple interfacing

#### **APPLICATIONS**

- Audio switching
- Battery powered systems
- Data acquisition
- Hi-Rel systems
- Sample-and-hold circuits
- Communication systems
- Automatic test equipment
- Medical instruments

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**





TRUTH TABLE						
Logic	DG441	DG442				
0	On	Off				
1	Off	On				

Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

Document Number: 70053

S11-1066-Rev. J, 30-May-11

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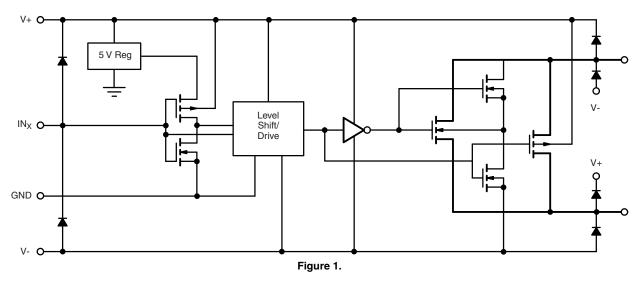
RDERING INFORMATION					
Temp. Range	Package	Part Number			
	40 min plantin DID	DG441DJ DG441DJ-E3			
	16-pin plastic DIP	DG442DJ DG442DJ-E3			
- 40 °C to 85 °C	16-pin narrow SOIC	DG441DY DG441DY-E3 DG441DY-T1 DG441DY-T1-E3			
	то-ритпаном зоно	DG442DY DG442DY-E3 DG442DY-T1 DG442DY-T1-E3			

ABSOLUTE MAXIMUM RATINGS					
Parameter		Limit	Unit		
V+ to V-		44			
GND to V-		25	V		
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first			
Continuous Current (any terminal)		30	mA		
Current, S or D (pulsed at 1 ms, 10 % duty cycle)		100			
Storage Temperature	(AK suffix)	- 65 to 150	- °C		
Storage remperature	(DJ, DY suffix)	- 65 to 125			
	16-pin plastic DIP <sup>c</sup>	450			
Power Dissipation (Package) <sup>b</sup>	16-pin CerDIP <sup>d</sup>	900	mW		
	16-pin narrow SOIC <sup>d</sup>	900			
	LCC-20 <sup>d</sup>	1200	1		

#### Notes:

- a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6 mW/°C above 75 °C.
- d. Derate 12 mW/°C above 75 °C.

## **SCHEMATIC DIAGRAM** Typical Channel





			Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V			_	uffix o 125 °C	_	uffix to 85 °C	
Parameter		Symbol	$V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^{f}$	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Uni
Analog Switch		•	<u> </u>		, , , , , , , , , , , , , , , , , , ,			1	I	
Analog Signal Range <sup>e</sup>		V <sub>ANALOG</sub>		Full		- 15	15	- 15	15	٧
Drain-Source On-Resistance		R <sub>DS(on)</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = ± 8.5 V V+ = 13.5 V, V- = - 13.5 V	Room Full	50		85 100		85 100	Ω
On-Resistance Match E Channels <sup>e</sup>	Between	$\Delta R_{DS(on)}$	$I_S = -10 \text{ mA}, V_D = \pm 10 \text{ V}$ V+ = 15 V, V- = -15 V	Room Full			4 5		4 5	52
Switch Off Leakage Cu	rrent	I <sub>S(off)</sub>	V+ = 16.5, V- = - 16.5 V	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	
Owner on Leakage ou	iiciii	I <sub>D(off)</sub>	$V_D = \pm 15.5 \text{ V}, V_S = \pm 15.5 \text{ V}$	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	nA
Channel On Leakage C	Current	$I_{D(on)}$	V+ = 16.5  V, V- = -16.5  V $V_S = V_D = \pm 15.5 \text{ V}$	Room Full	± 0.08	- 0.5 - 40	0.5 40	- 0.5 - 10	0.5 10	
Digital Control										
Input Current V <sub>IN</sub> Low		I <sub>IL</sub>	V <sub>IN</sub> under test = 0.8 V, All Other = 2.4 V	Full	- 0.01	- 500	500	- 500	500	n/
Input Current V <sub>IN</sub> High		I <sub>IH</sub>	V <sub>IN</sub> under test = 2.4 V All Other = 0.8 V	Full	0.01	- 500	500	- 500	500	11/-
<b>Dynamic Characterist</b>	ics									
Turn-On Time		t <sub>ON</sub>	$R_L = 1 \text{ k}\Omega, C_L = 35 \text{ pF}$	Room	150		250		250	
Turn-Off Time	DG441	t <sub>OFF</sub>	$V_{S} = \pm 10 \text{ V}$	Room	90		120		120	ns
	DG442		See Figure 2	Room	110		210		210	
Charge Injection <sup>e</sup>		Q	$C_L = 1 \text{ nF, } V_S = 0 \text{ V}$ $V_{gen} = 0 \text{ V, } R_{gen} = 0 \Omega$	Room	- 1					рC
Off Isolation <sup>e</sup>		OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	60					
Crosstalk (Channel-to-Channel)		X <sub>TALK</sub>	f = 1 MHz	Room	100					dE
Source Off Capacitance	e <sup>e</sup>	C <sub>S(off)</sub>	f = 1 MHz	Room	4					
Drain Off Capacitance <sup>e</sup>		C <sub>D(off)</sub>	1 – 1 101112	Room	4					рF
Channel On Capacitance <sup>e</sup> C <sub>E</sub>		C <sub>D(on)</sub>	V <sub>ANALOG</sub> = 0 V	Room	16					
Power Supplies										
Positive Supply Current	t	l+		Full	15		100		100	
Negative Supply Currer	nt	l-	V+ = 16.5 V, V- = - 16.5 V V <sub>IN</sub> = 0 or 5 V	Room Full	- 0.0001	- 1 - 5		- 1 - 5		μ/
Ground Current		I <sub>GND</sub>	1	Full	- 15	- 100		- 100		1



SPECIFICATIONS <sup>a</sup> (Single Supply)									
				Unless Otherwise Specified - 55 °C to 125 °C			<b>D Suffix</b> C - 40 °C to 85 °C		
Parameter	Symbol	V+ = 12 V, V- = 0 V $V_{IN} = 2.4 V, 0.8 V^f$	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit
Analog Switch									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		0	12	0	12	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$I_S = -10 \text{ mA}, V_D = 3 \text{ V}, 8 \text{ V}$ V+ = 10.8 V	Room Full	100		160 200		160 200	Ω
Dynamic Characteristics			•					•	
Turn-On Time	t <sub>ON</sub>	$R_L = 1 \text{ k}\Omega, C_L = 35 \text{ pF}$	Room	300		450		450	
Turn-Off Time	t <sub>OFF</sub>	V <sub>S</sub> = 8 V See Figure 2	Room	60		200		200	ns
Charge Injection	Q	$C_L = 1nF, V_{gen} = 6 V, R_{gen} = 0 \Omega$	Room	2					рС
Power Supplies	Power Supplies								•
Positive Supply Current	l+		Full	15		100		100	
Negative Supply Current	I-	V+ = 13.2 V, V- = 0 V $V_{IN} = 0 \text{ or } 5 V$	Room Full	- 0.0001	- 1 - 100		- 1 - 100		μΑ
Ground Current	I <sub>GND</sub>		Full	- 15	- 100		- 100		

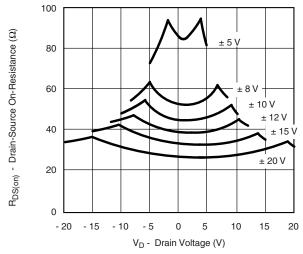
#### Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25  $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.

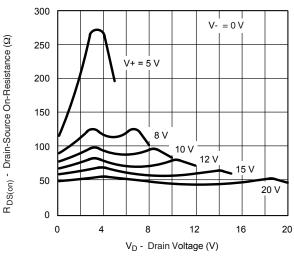
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



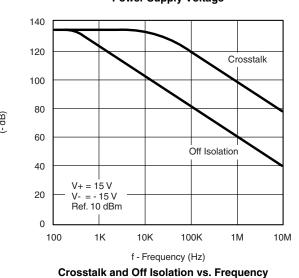
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



R<sub>DS(on)</sub> vs. V<sub>D</sub> and Power Supply Voltage

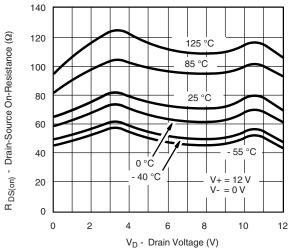


R<sub>DS(on)</sub> vs. V<sub>D</sub> and Unipolar Power Supply Voltage

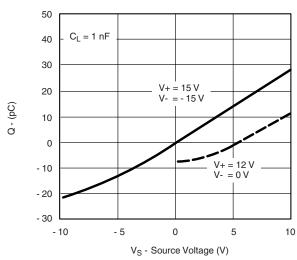


80 V+ = 15 V 70  $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$  - Drain-Source On-Resistance  $(\Omega)$ V - = -15 V60 125 °C 50 85 °C 25 °C 40 30 20 0°C 55 °C 10 0 - 15 - 10 - 5 0 10 15 V<sub>D</sub> - Drain Voltage (V)

R<sub>DS(on)</sub> vs. V<sub>D</sub> and Temperature



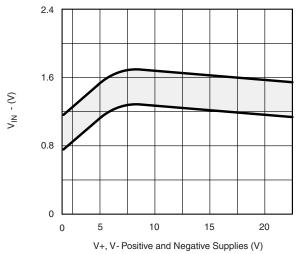
R<sub>DS(on)</sub> vs. V<sub>D</sub> and Temperature (Single 12-V Supply)



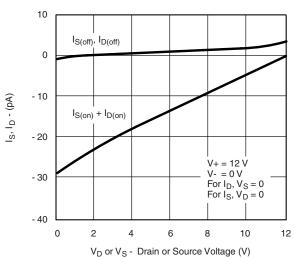
Charge Injection vs. Source Voltage

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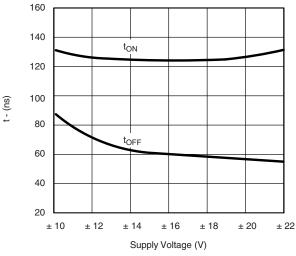
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



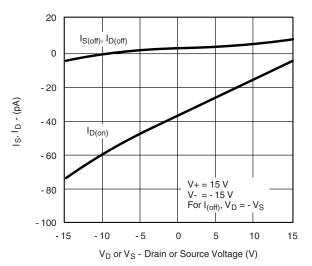
Switching Threshold vs. Supply Voltage



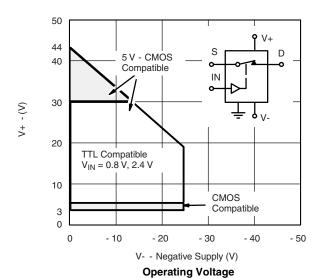
Source/Drain Leakage Currents (Single 12 V Supply)



Switching Time vs. Power Supply Voltage



Source/Drain Leakage Currents



400 V- = 0 V

400

200

100

topic

14

 $\label{eq:VS-Source-Voltage} V_S \text{ - Source Voltage (V)} \\ \textbf{Switching Time vs. Power Supply Voltage}$ 

16

20

22

18

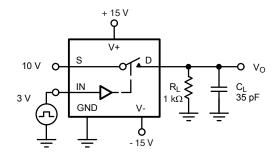
8

10

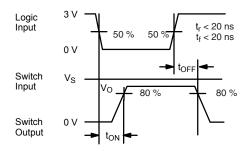
500



## **TEST CIRCUITS**

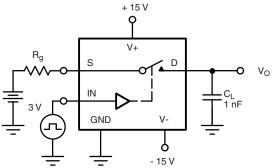


 $\boldsymbol{C}_{\boldsymbol{L}}$  (includes fixture and stray capacitance)



Note: Logic input waveform is inverted for DG442.

Figure 2. Switching Time



+ 15 V

Figure 3. Charge Injection

 $C = 1 \text{ mF tantalum in parallel with 0.01 mF ceramic} \\ + 15 \text{ V} \\ \hline \\ O \text{ V, 2.4 V} \\ \hline \\ O \text{ V, 2.4 V} \\ \hline \\ C \text{ GND} \\ \hline \\ C \text{ C} \\ \hline \\ C \text{ Fe bypass} \\ \hline \\ C \text{ For all of the condition} \\ \hline \\ C \text{ Tall K Isolation} \\ \hline \\ C \text{ Tall by pass} \\ \hline \\ C \text{ Tall by Double of the condition} \\ \hline \\ C \text{ Tall by Dass} \\ C \text{ T$ 

Figure 4. Crosstalk

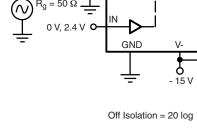


Figure 5. Off Isolation

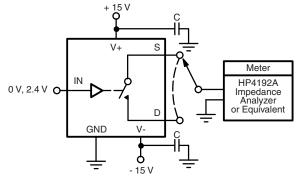


Figure 6. Source/Drain Capacitances

## **APPLICATIONS**

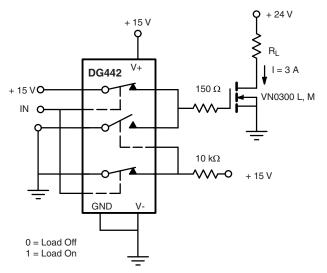


Figure 7. Power MOSFET Driver

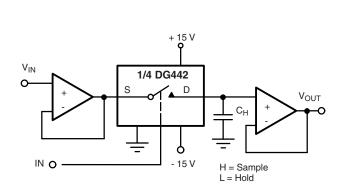


Figure 8. Open Loop Sample-and-Hold

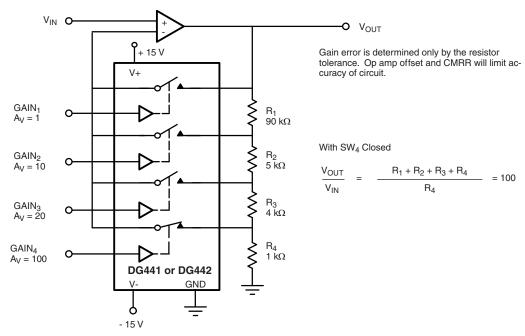
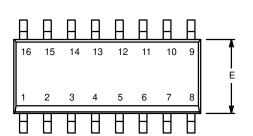


Figure 9. Precision-Weighted Resistor Programmable-Gain Amplifier

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70053.



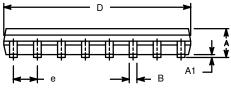
SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012

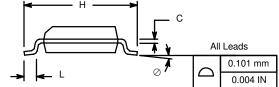


	MILLIMETERS		INC	HES
Dim	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
В	0.38	0.51	0.015	0.020
С	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
е	1.27	BSC	0.050	BSC
Н	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
0	0°	8°	0°	8°
FCN: S-0	3946—Rev F	09lul-01		

ECN: S-03946—Rev. F, 09-Jul-01

DWG: 5300

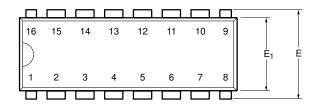


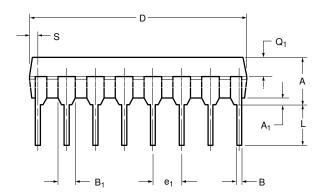


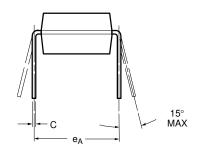
Document Number: 71194 www.vishay.com 02-Jul-01



PDIP: 16-LEAD





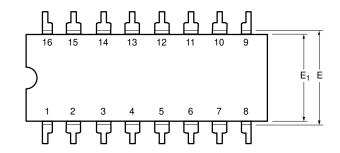


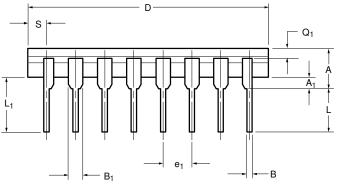
	MILLIN	IETERS	INC	HES		
Dim	Min	Max	Min	Max		
Α	3.81	5.08	0.150	0.200		
A <sub>1</sub>	0.38	1.27	0.015	0.050		
В	0.38	0.51	0.015	0.020		
B <sub>1</sub>	0.89	1.65	0.035	0.065		
С	0.20	0.30	0.008	0.012		
D	18.93	21.33	0.745	0.840		
E	7.62	8.26	0.300	0.325		
E <sub>1</sub>	5.59	7.11	0.220	0.280		
e <sub>1</sub>	2.29	2.79	0.090	0.110		
e <sub>A</sub>	7.37	7.87	0.290	0.310		
L	2.79	3.81	0.110	0.150		
Q <sub>1</sub>	1.27	2.03	0.050	0.080		
S	0.38	1.52	.015	0.060		
	ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482					

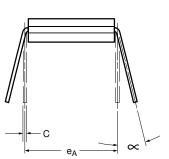
Document Number: 71261 www.vishay.com 06-Jul-01



## **CERDIP: 16-LEAD**







	MILLIM	IETERS	INC	HES		
Dim	Min	Max	Min	Max		
Α	4.06	5.08	0.160	0.200		
A <sub>1</sub>	0.51	1.14	0.020	0.045		
В	0.38	0.51	0.015	0.020		
B <sub>1</sub>	1.14	1.65	0.045	0.065		
С	0.20	0.30	0.008	0.012		
D	19.05	19.56	0.750	0.770		
E	7.62	8.26	0.300	0.325		
E <sub>1</sub>	6.60	7.62	0.260	0.300		
e <sub>1</sub>	2.54 BSC		0.100	BSC		
e <sub>A</sub>	7.62 BSC		0.300	BSC		
L	3.18	3.81	0.125	0.150		
L <sub>1</sub>	3.81	5.08	0.150	0.200		
Q <sub>1</sub>	1.27	2.16	0.050	0.085		
S	0.38	1.14	0.015	0.045		
∞	0°	15°	0°	15°		
ECN: S-03946—Rev. G, 09-Jul-01						

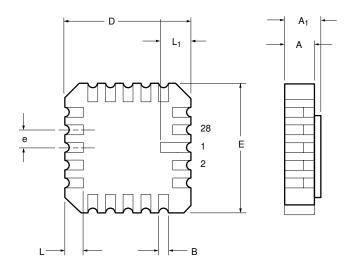
DWG: 5403

www.vishay.com Document Number: 71282 03-Jul-01





## **20-LEAD LCC**



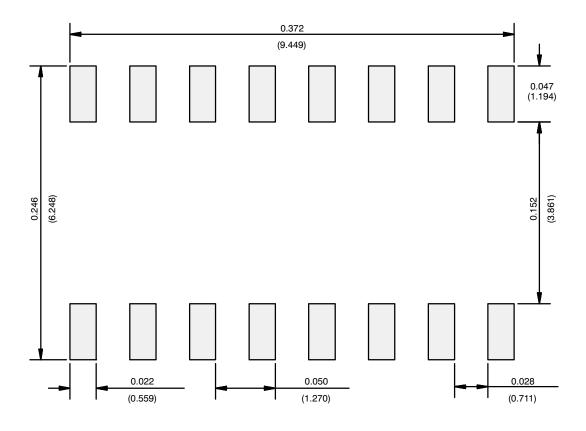
	MILLIM	IETERS	INC	HES		
D:		_	_			
Dim	Min	Max	Min	Max		
A	1.37	2.24	0.054	0.088		
A <sub>1</sub>	1.63	2.54	0.064	0.100		
В	0.56	0.71	0.022	0.028		
D	8.69	9.09	0.342	0.358		
E	8.69	9.09	0.442	0.358		
е	1.27 BSC		0.050	BSC		
L	1.14	1.40	0.045	0.055		
L <sub>1</sub>	1.96	2.36	0.077	0.093		
ECN: S-03946—Rev. B, 09-Jul-01						

DWG: 5321

Document Number: 71290 www.vishay.com 02-Jul-01



## **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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